



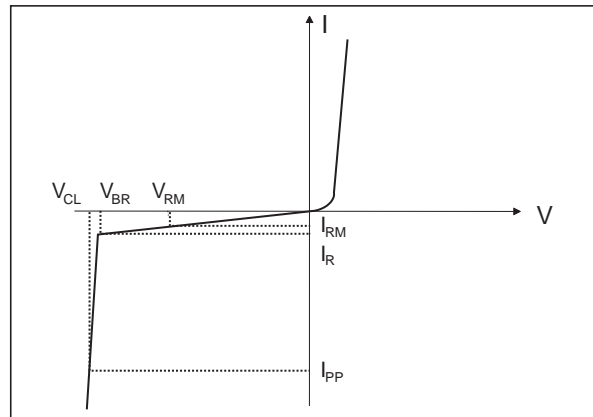
# EMIF10-1K010F1

## ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

Symbol	Parameter and test conditions	Value	Unit
$T_j$	Junction temperature	125	$^{\circ}\text{C}$
$T_{op}$	Operating temperature range	-40 to + 85	$^{\circ}\text{C}$
$T_{stg}$	Storage temperature range	-55 to +150	$^{\circ}\text{C}$

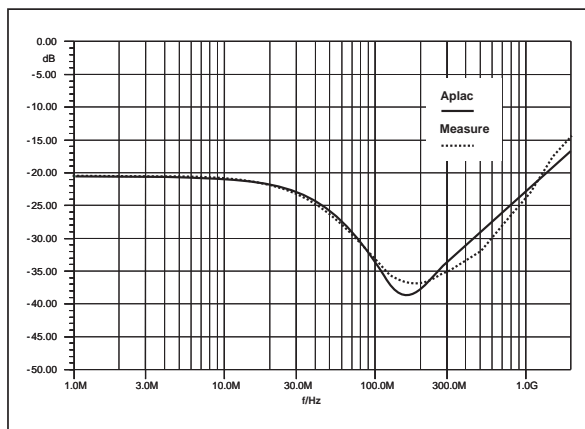
## ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

Symbol	Parameters
$V_{BR}$	Breakdown voltage
$I_{RM}$	Leakage current @ $V_{RM}$
$V_{RM}$	Stand-off voltage
$V_{CL}$	Clamping voltage
$R_d$	Dynamic impedance
$I_{PP}$	Peak pulse current
$R_{I/O}$	Series resistance between Input & Output
$C_{line}$	Input capacitance per line

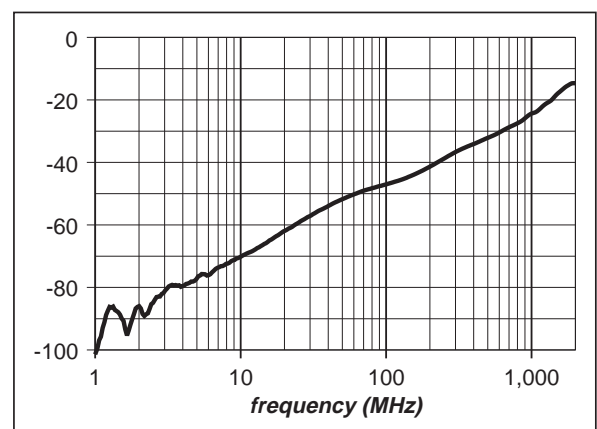


Symbol	Test conditions	Min	Typ	Max	Unit
$V_{BR}$	$I_R = 1\text{ mA}$	6	8	10	V
$I_{RM}$	$V_{RM} = 3\text{ V}$ per line			500	nA
$R_{I/O}$		900	1000	1100	$\Omega$
$C_{line}$	At 0V bias	80	100	120	pF

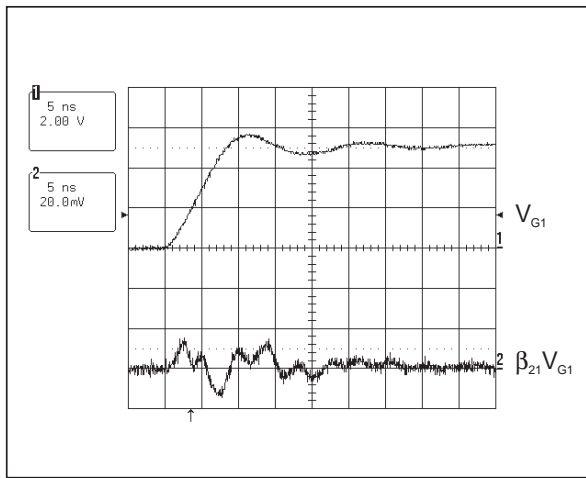
**Fig. 1:** S21(dB) attenuation measurement and Aplac simulation.



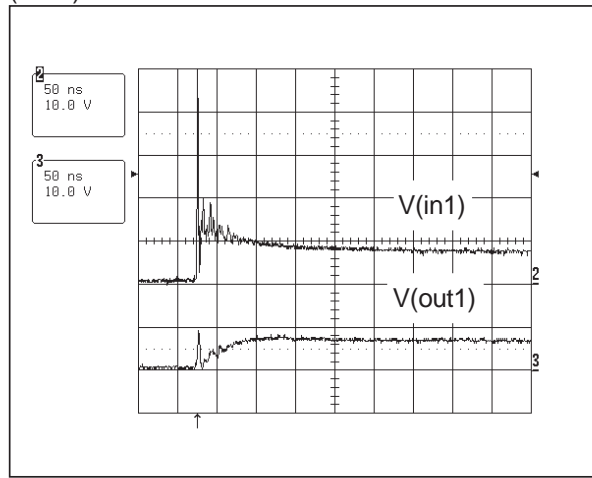
**Fig. 2:** Analog crosstalk measurements.



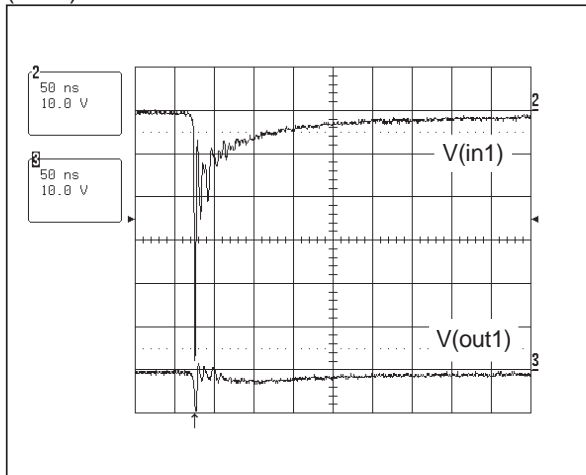
**Fig. 3:** Digital crosstalk measurement.



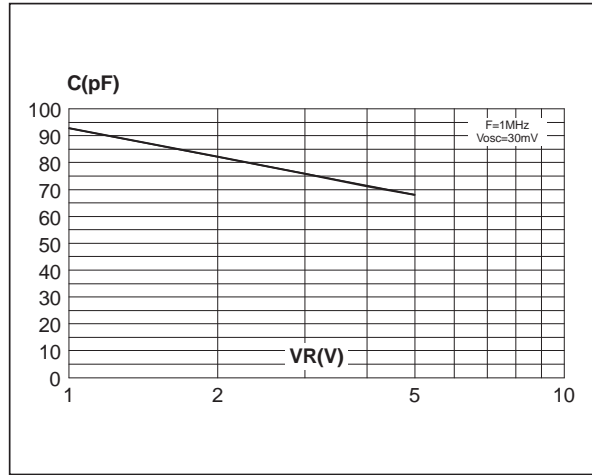
**Fig. 4:** ESD response to IEC61000-4-2 (+15kV air discharge) on one input  $V(in)$  and on one output ( $V(out)$ ).



**Fig. 5:** ESD response to IEC61000-4-2 (-15kV air discharge) on one input  $V(in)$  and on one output ( $V(out)$ ).

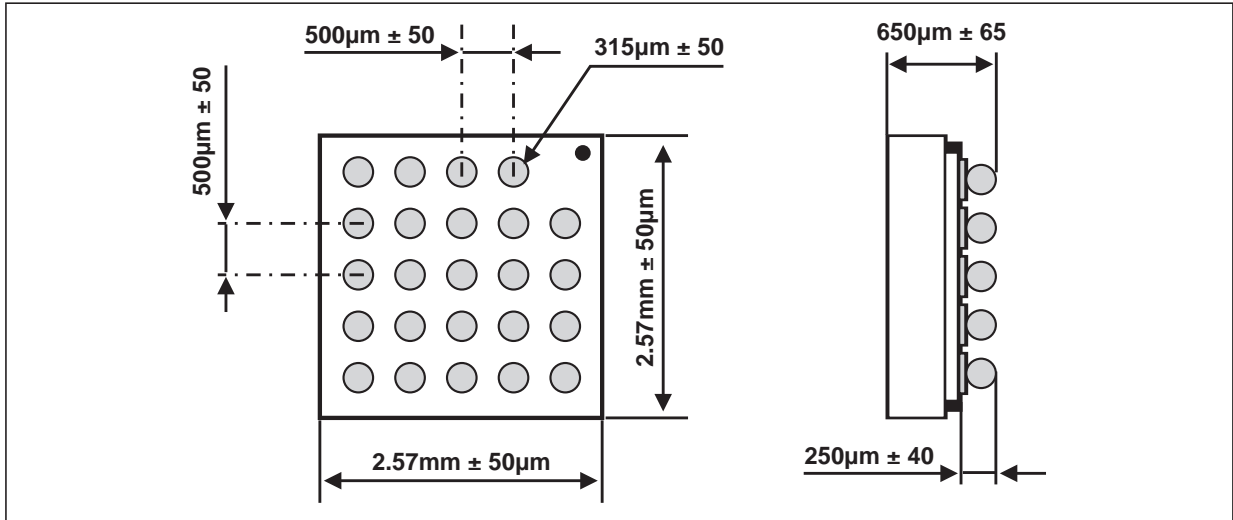


**Fig. 6:** Line capacitance versus applied voltage.

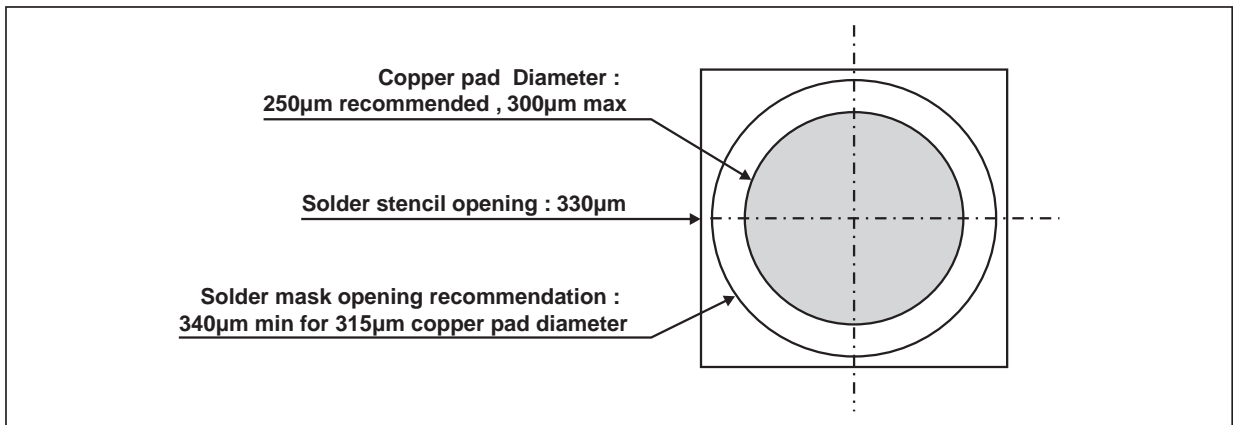




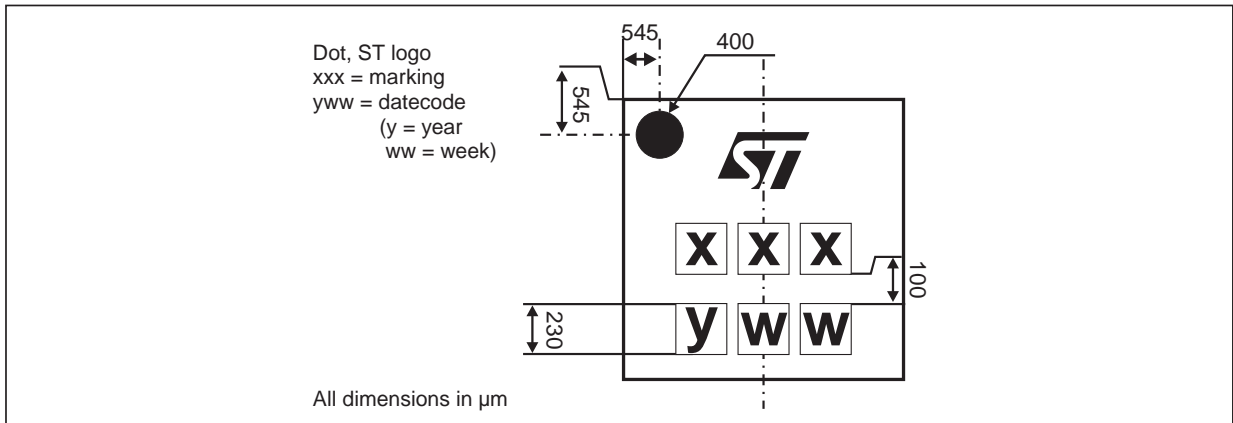
**PACKAGE MECHANICAL DATA  
FLIP CHIP**



**FOOT PRINT RECOMMENDATIONS**

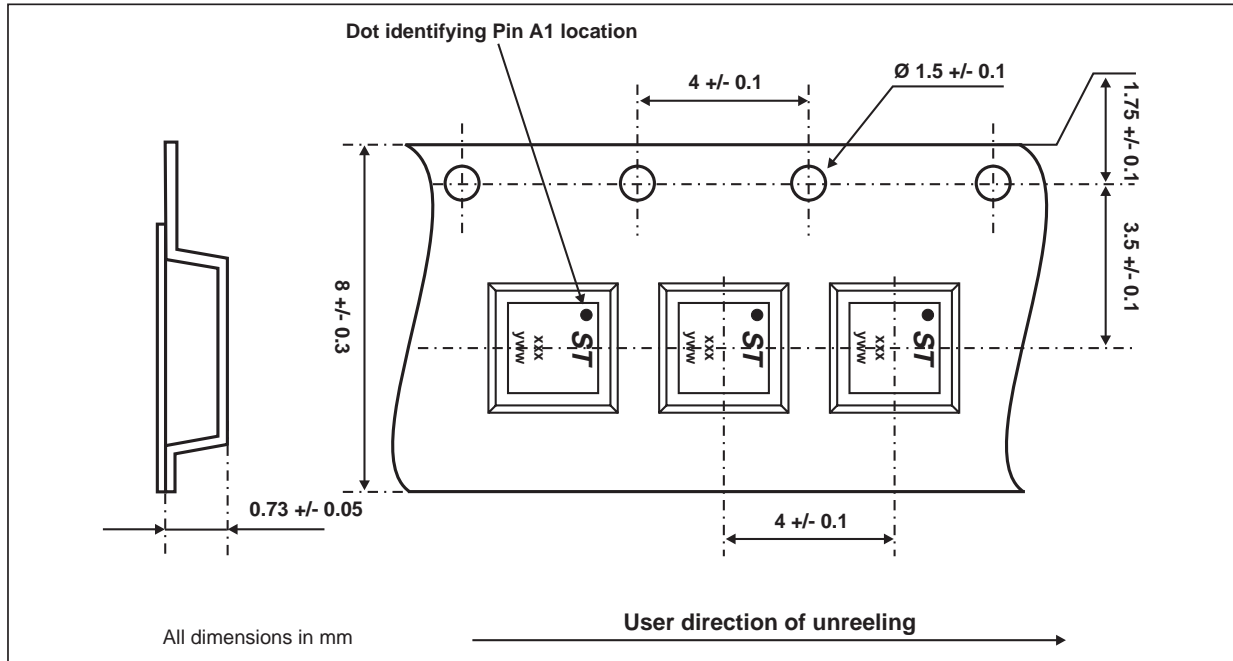


**MARKING**



# EMIF10-1K010F1

## PACKING



## OTHER INFORMATION

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
EMIF10-1K010F1	FDT	Flip Chip	9.2 mg	5000	Tape & reel (7")

**Note:** More information are available in the application notes:

- AN1235: "Flip-Chip: Package description and recommendations for use"
- AN1751: "EMI Filters: Recommendations and measurements"

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